



The HM Series is ideal for high-volume, low and medium pressure, harsh-media applications.

COMPANY: Merit Sensor is a leader in piezoresistive pressure sensing and partners with clients to create high performing solutions for a variety of applications and industries.

SENTIUM: Merit Sensor products incorporate a proprietary Sentium® technology, developed to provide a best-in-class operating temperature range (-40°C to 150°C) and superior stability.

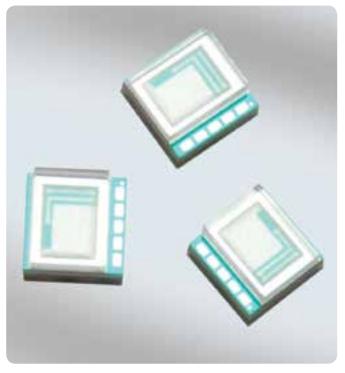
TECHNOLOGY: Merit Sensor utilizes a piezoresistive Wheatstone bridge in a design that anodically bonds glass to a chemically etched silicon diaphragm. All products are RoHS compliant.

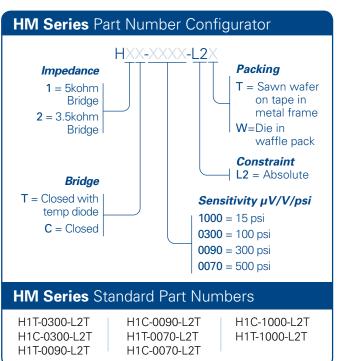
CAPABILITIES: Merit Sensor designs, engineers, fabricates, dices, assembles, and tests products from a state-of-the-art facility near Salt Lake City, Utah.

FEATURES

Range	15 to 500 psi (1 to 34.5 bar; 103 to 3,447 KPa)
Type	Absolute; pressurized from cavity side
Media	Air, gases and liquids that are compatible with silicon and glass
Shipping	Wafers on tape, waffle pack
Flexibility	Sensitivity, resistance, bridge, constraint, etc.

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Flexibility	Sensitivity, resistance, bridge, constraint, etc.				
BENEFITS					
Performance	Enjoy best-in-class performance due to Merit's proprietary Sentium technology				
Cost	Save money over time with high-performing die				
Security	Feel confident doing business with an experienced company backed by a solid parent company (NASDAQ: MMSI)				
Speed	Get to market quickly with creative and flexible solutions				
Service	Experience prompt, personal, and professional support				







SPECIFICATIONS

Parameter	Minimum	Typical	Maximum	Units	Notes			
Electrical & Environmental								
Excitation (In)		5	15	V	Maximum: 3 mA			
Impedance	4000	5000	6000	Ω	Optional: 3,500 +/- 500			
Operating Temperature	-40		150	°C	Sentium® technology			
Storage Temperature	-55		160	°C				
Performance								
Offset	-10	0	10	mV/V	Zero pressure; gage only; @25°C			
Non-linearity	-0.2	0	0.2	% FSO	Best Fit Straight Line; @25°C			
Pressure Hysteresis	-0.1	0	0.1	% FSO	@25°C			
Temp Coeff – Zero	-25	0	25	μV/V/°C	-40°C to 150°C			
Temp Coeff – Resistance	2300	2800	3300	PPM/°C	-40°C to 150°C			
Temp Coeff – Sensitivity	-1500	-2200	-2500	PPM/°C	-40°C to 150°C			
U _{diode} @ I _S = 40uA	460	530	600	mV				
TC of U _{diode}	-2.5	-2.2	-2.0	mV/°C				
Long-Term Stability	-0.2	0	0.2	% FSO				
Burst Pressure	5X				Full scale pressure			
Burst Pressure (500 psi part)	1500			psi				
Full-Scale Output (@ 5 volts excitation)								
15 psi (1 bar; 103 KPa)	60	75	90	mV				
100 psi (6.9 bar; 689.5 KPa)	120	150	180	mV				
300 psi (20.7 bar; 2,068 KPa)	110	135	160	mV	Other outputs available upon request			
500 psi (34.5 bar; 3,447 KPa)	140	175	210	mV				

DIMENSIONS (millimeters, post cut)

Top View 2.1 2.1 0.4 0.3 0.1 0.3 0.1 0.3 0.1 0.3 Side View 1.4 0.9 0.4 Glass Silicon Glass

ELECTRICAL

